Acta Crystallographica Section E Structure Reports Online

ISSN 1600-5368

Peter G. Jones,^a* Peter Bubenitschek,^b Henning Hopf^b and Reiner Stamm^b

^aInstitut für Anorganische und Analytische Chemie, Technische Universität Braunschweig, Postfach 3329, 38023 Braunschweig, Germany, and ^bInstitut für Organische Chemie, Technische Universität Braunschweig, Postfach 3329, 38023 Braunschweig, Germany

Correspondence e-mail: p.jones@tu-bs.de

Key indicators

Single-crystal X-ray study T = 178 K Mean σ (C–C) = 0.003 Å R factor = 0.042 wR factor = 0.115 Data-to-parameter ratio = 24.9

For details of how these key indicators were automatically derived from the article, see http://journals.iucr.org/e.

© 2003 International Union of Crystallography Printed in Great Britain – all rights reserved The title compound, $C_{16}H_{30}Si_2$, possesses crystallographic inversion symmetry. The allenic bond lengths are 1.309 (2) and 1.314 (2) Å.

Received 9 December 2002 Accepted 11 December 2002 Online 10 January 2003

Comment

As the cumulogues of conjugated dienes, conjugated bisallenes are of interest for preparative (*e.g.* as partners in cycloaddion reactions; Sankararaman *et al.*, 2000) and structural reasons. The structure of the parent system 1,2,4,5hexatetraene in solution and in the gas phase has been described (Christensen *et al.*, 1973; Traetteberg *et al.*, 1973). Since structural data for this class of hydrocarbon are still scarce, we decided to prepare 2,7-dimethyl-4,5-bis(trimethylsilyl)octa-2,3,5,6-tetraene, (2), a fully substituted bis-allene, and investigate it by X-ray structural analysis. As a precursor we used 2,7-dimethylocta-2,4,5,6-tetraene, (1), whose solidstate structure we have reported recently (Jones *et al.*, 2002).



The structure of (2) is shown in Fig. 1. The molecule possesses a crystallographic inversion centre at the midpoint of the C4–C4ⁱ bond [symmetry code: (i) 1 - x, -y, 1 - z]. Bond lengths and angles [*e.g.* the allenic bond lengths of 1.309 (2) and 1.314 (2) Å] may be considered normal [*cf.* 1.3067 (16) and 1.3126 (16) Å in (1); Jones *et al.*, 2002]. The planes C1/2/3/5 and Si/C3/4/4ⁱ are mutually perpendicular [interplanar angle 88.49 (8)°].

The packing (Fig. 2) is unexceptional. The shortest $H \cdots H$ contacts are $H6A \cdots H8A(1 - x, 1 - y, -z) = 2.53 \text{ Å}$ and $H7B \cdots H8C(1 + x, y, z) = 2.52 \text{ Å}$.

Experimental

Compound (1) was metallated with *n*-butyllithium in thf in the presence of tetramethylethylenediamine, and the resulting dianion was then quenched with trimethylsilylchloride (Stamm, 1992). Recrystallization of (2) from pentane afforded single crystals.

Crystal data		
$C_{16}H_{30}Si_2$	Z = 1	
$M_r = 278.58$	$D_x = 0.986 \text{ Mg m}^{-3}$	
Triclinic, P1	Mo $K\alpha$ radiation	
a = 6.363 (2) Å	Cell parameters from 50	
b = 8.963 (2) Å	reflections	
c = 9.157 (3) Å	$\theta = 10-11.5^{\circ}$	
$\alpha = 70.76 \ (2)^{\circ}$	$\mu = 0.18 \text{ mm}^{-1}$	
$\beta = 72.13 \ (2)^{\circ}$	T = 178 (2) K	
$\gamma = 83.41 \ (2)^{\circ}$	Prism, colourless	
$V = 469.2 (2) \text{ Å}^3$	$0.70 \times 0.25 \times 0.15 \text{ mm}$	



Figure 1

The molecule of compound (2) in the crystal. Ellipsoids are drawn at the 50% probability level. H-atom radii are arbitrary.

 $h = 0 \rightarrow 8$

 $k = -11 \rightarrow 11$

 $l=-11\rightarrow 11$

3 standard reflections

every 147 reflections

intensity decay: none

 $w = 1/[\sigma^2(F_o^2) + (0.056P)^2]$

where $P = (F_o^2 + 2F_c^2)/3$

+ 0.1101P]

 $(\Delta/\sigma)_{\rm max} < 0.001$

 $\Delta \rho_{\rm max} = 0.29 \text{ e } \text{\AA}^{-3}$

 $\Delta \rho_{\rm min} = -0.21 \text{ e } \text{\AA}^{-3}$

Data collection

Nicolet R3 diffractometer ω scans 2355 measured reflections 2162 independent reflections 1613 reflections with $I > 2\sigma(I)$ $R_{\text{int}} = 0.015$ $\theta_{\text{max}} = 27.6^{\circ}$

Refinement

Refinement on F^2 $R[F^2 > 2\sigma(F^2)] = 0.042$ $wR(F^2) = 0.115$ S = 1.022162 reflections 87 parameters H-atom parameters constrained

Table 1

Selected geometric parameters (Å, °).

C2-C3 C3-C4	1.309 (2) 1.314 (2)	C4-C4 ⁱ	1.501 (3)
C2-C3-C4	174.86 (18)	$\begin{array}{c} C3{-}C4{-}Si\\ C4^i{-}C4{-}Si\end{array}$	116.38 (13)
$C3-C4-C4^{i}$	121.56 (19)		122.06 (16)

Symmetry code: (i) 1 - x, -y, 1 - z.





Methyl H atoms were identified in difference syntheses, idealized and then refined using rigid methyl groups (C-H = 0.98 Å and H-C-H = 109.5°), allowed to rotate but not tip.

Data collection: P3 (Nicolet, 1987); cell refinement: P3; data reduction: XDISK (Nicolet, 1987); program(s) used to solve structure: SHELXS97 (Sheldrick, 1990); program(s) used to refine structure: SHELXL97 (Sheldrick, 1997); molecular graphics: XP (Siemens, 1994); software used to prepare material for publication: SHELXL97.

Financial support from the Fonds der Chemischen Industrie is gratefully acknowledged. We thank Mr A. Weinkauf for technical assistance.

References

Christensen, D. H., Hopf, H., Klaeboe, P. & Powell, D. L. (1973). Spectrochim. Acta Part A, 29, pp. 7–9.

Jones, P. G., Bubenitschek, P., Hopf, H. & Stamm, R. (2002). Acta Cryst. E58, 0277–0278.

Nicolet (1987). P3 and XDISK. Nicolet Instrument Corporation, Madison, Wisconsin, USA.

Sankararaman, S., Hopf, H., Dix., I. & Jones, P. G. (2000). Eur. J. Org. Chem. pp. 2699–2702.

Sheldrick, G. M. (1990). Acta Cryst. A46, 467-473.

Sheldrick, G. M. (1997). SHELXL97. University of Göttingen, Germany.

Siemens (1994). XP. Version 5.03. Siemens Analytical X-ray Instruments Inc., Madison, Wisconsin, USA.

Stamm, R. (1992). PhD thesis, Technical University of Braunschweig, Germany.

Traetteberg, M., Paulen, G. & Hopf, H. (1973). Acta Chem. Scand. 27, 2227-2229.